

V_{DSS}	60V
$R_{DS(on)}(Max.)$	61mΩ
I_D	±12A
P_D	14.8W

●Features

- 1) Low on - resistance.
- 2) Small Surface Mount Package.
- 3) Pb-free lead plating ; RoHS compliant

●Application

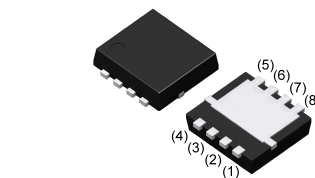
Switching

●Absolute maximum ratings ($T_a = 25^{\circ}C$)

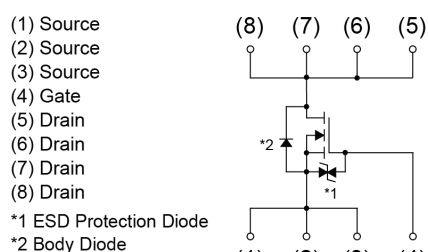
Parameter		Symbol	Value	Unit
Drain - Source voltage		V_{DSS}	60	V
Continuous drain current	$T_c = 25^{\circ}C$	I_D^{*1}	±12	A
	$T_a = 25^{\circ}C$	I_D	±5	A
Pulsed drain current		$I_{D,pulse}^{*2}$	±20	A
Gate - Source voltage		V_{GSS}	±20	V
Avalanche energy, single pulse		E_{AS}^{*3}	3.9	mJ
Avalanche current		I_{AS}^{*3}	5.0	A
Power dissipation		P_D^{*1}	14.8	W
		P_D^{*4}	2.0	W
Junction temperature		T_j	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

●Outline

HSMT8



●Inner circuit



●Packaging specifications

Type	Packing	Embossed Tape
	Reel size (mm)	330
	Tape width (mm)	12
	Basic ordering unit (pcs)	3000
	Taping code	TB
	Marking	L050GN

● Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - ambient	R_{thJA}^{*4}	-	-	62.5	°C/W
Thermal resistance, junction - case	R_{thJC}^{*1}	-	-	8.4	°C/W

● Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 1mA$	60	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$	$I_D = 1mA$ referenced to 25°C	-	60	-	mV/°C
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 60V, V_{GS} = 0V$	-	-	10	μA
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±10	μA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 25\mu A$	1.0	-	2.5	V
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_j}$	$I_D = 1mA$ referenced to 25°C	-	-5.6	-	mV/°C
Static drain - source on - state resistance	$R_{DS(on)}^{*5}$	$V_{GS} = 10V, I_D = 5A$	-	43	61	mΩ
		$V_{GS} = 6.0V, I_D = 5A$	-	47	66	
		$V_{GS} = 4.5V, I_D = 5A$	-	61	86	
Gate input resistance	R_G	$f=1MHz$, open drain	-	1.9	-	Ω
Forward Transfer Admittance	$ Y_{fs} ^{*5}$	$V_{DS} = 5V, I_D = 5A$	3.5	-	-	S

*1 $T_c = 25^\circ\text{C}$

*2 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

*3 $L \approx 0.2mH$, $V_{DD} = 30V$, $R_G = 25\Omega$, STARTING $T_{ch} = 25^\circ\text{C}$ Fig.3-1,3-2

*4 Mounted on a ceramic board (30×30×0.8mm)

* Limited only by maximum chamber temperature allowed.

*5 Pulsed

●Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	C_{iss}	$V_{GS} = 0V$	-	300	-	pF
Output capacitance	C_{oss}	$V_{DS} = 30V$	-	52	-	
Reverse transfer capacitance	C_{rss}	$f = 1\text{MHz}$	-	18	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \approx 30V, V_{GS} = 10V$	-	7.4	-	ns
Rise time	t_r^{*5}	$I_D = 2.5A$	-	4.9	-	
Turn - off delay time	$t_{d(off)}^{*5}$	$R_L \approx 12\Omega$	-	17.4	-	
Fall time	t_f^{*5}	$R_G = 10\Omega$	-	3.7	-	

●Gate charge characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions		Values			Unit
				Min.	Typ.	Max.	
Total gate charge	Q_g^{*5}	$V_{DD} \approx 30V$ $I_D = 5A$	$V_{GS} = 10V$	-	5.3	-	nC
Gate - Source charge	Q_{gs}^{*5}		$V_{GS} = 4.5V$	-	2.8	-	
Gate - Drain charge	Q_{gd}^{*5}			-	1.1	-	
				-	1.0	-	

●Body diode electrical characteristics (Source-Drain) ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Body diode continuous forward current	I_S	$T_a = 25^\circ\text{C}$	-	-	1.67	A
Body diode pulse current	I_{SP}^{*2}		-	-	20	A
Forward voltage	V_{SD}^{*5}	$V_{GS} = 0V, I_S = 1.67A$	-	-	1.2	V
Reverse recovery time	t_{rr}^{*5}	$I_S = 5A, V_{GS}=0V$	-	26	-	ns
Reverse recovery charge	Q_{rr}^{*5}	$di/dt = 100A/\mu s$	-	21	-	nC

●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

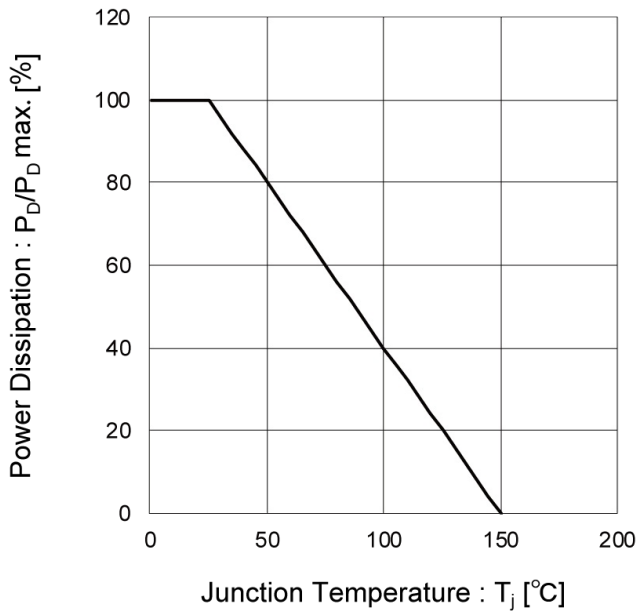


Fig.2 Maximum Safe Operating Area

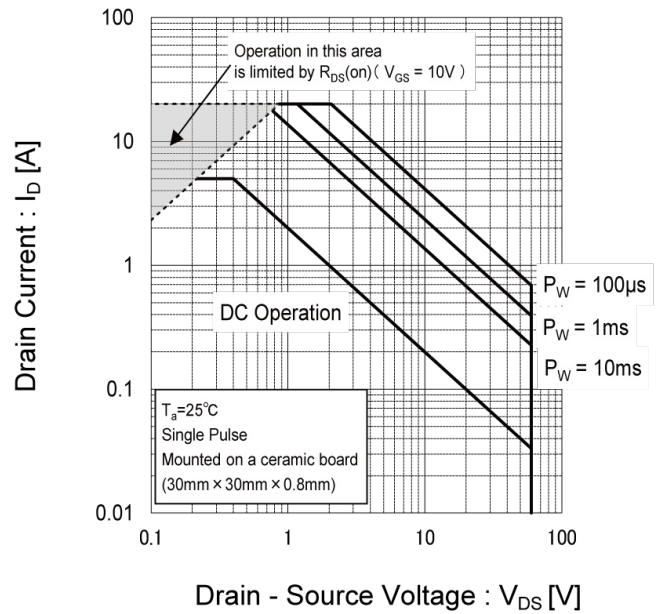


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

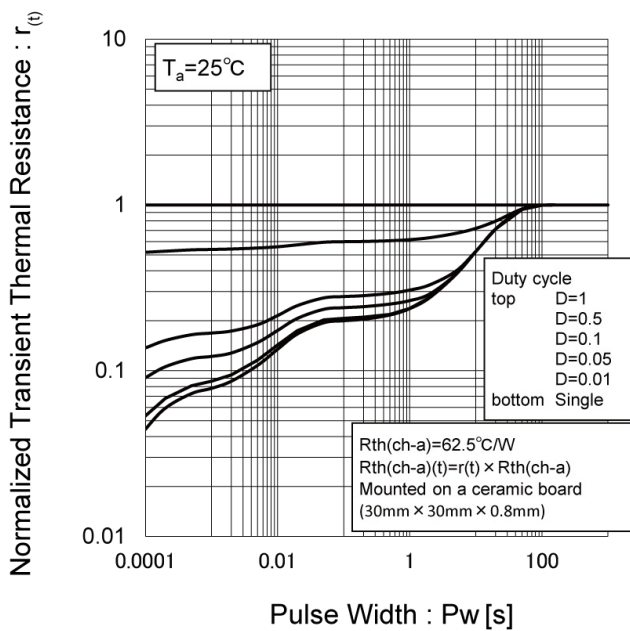
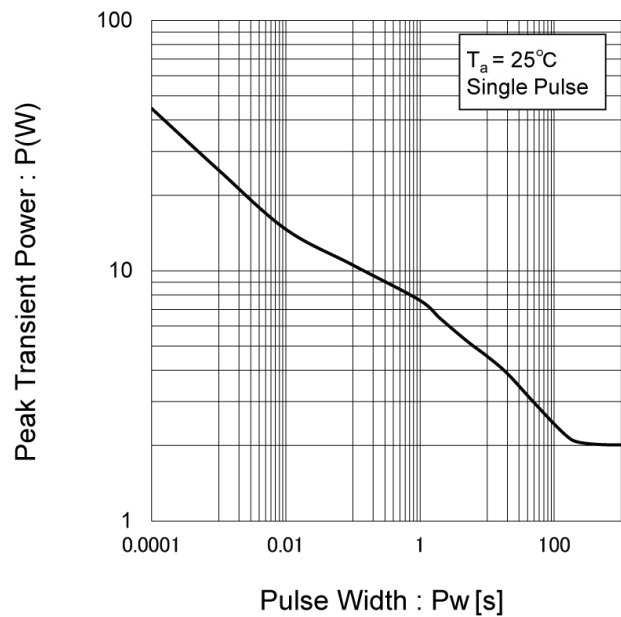


Fig.4 Single Pulse Maximum Power dissipation



●Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

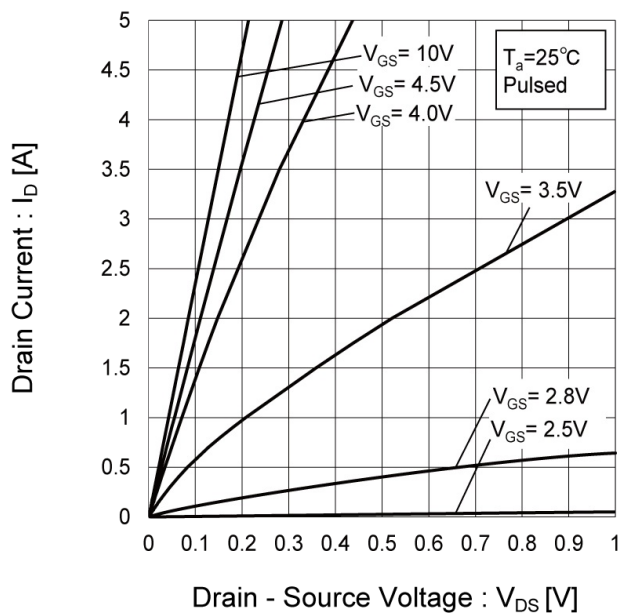


Fig.6 Typical Output Characteristics(II)

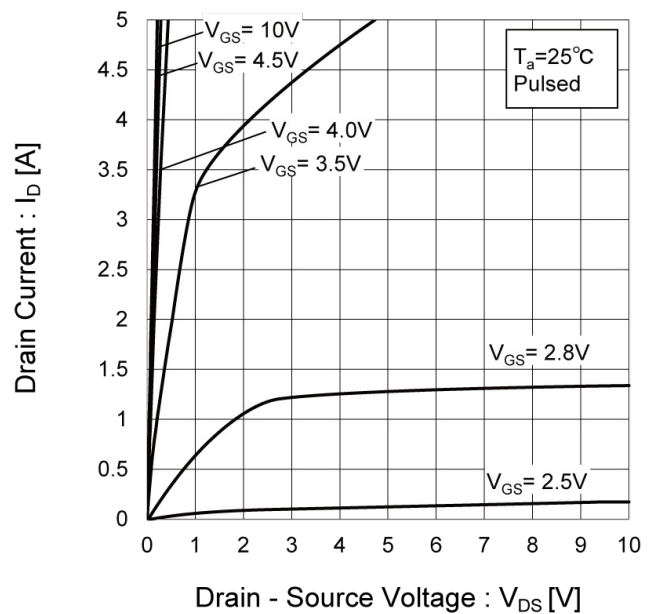
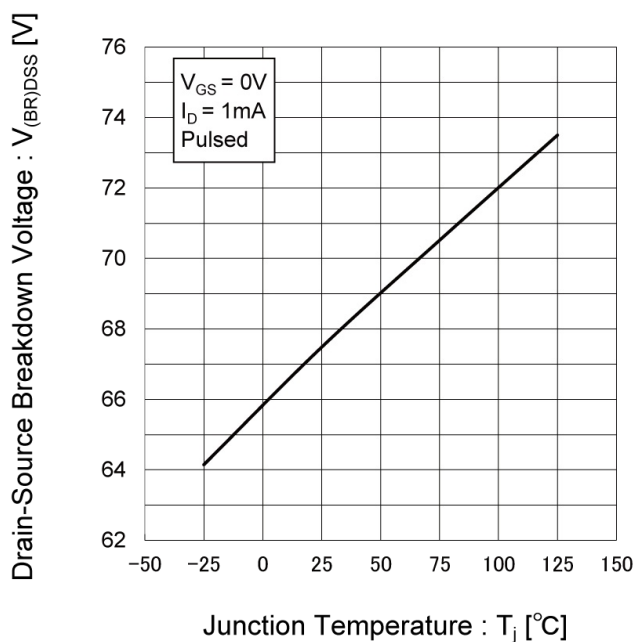


Fig.7 Breakdown Voltage vs. Junction Temperature



●Electrical characteristic curves

Fig.8 Typical Transfer Characteristics

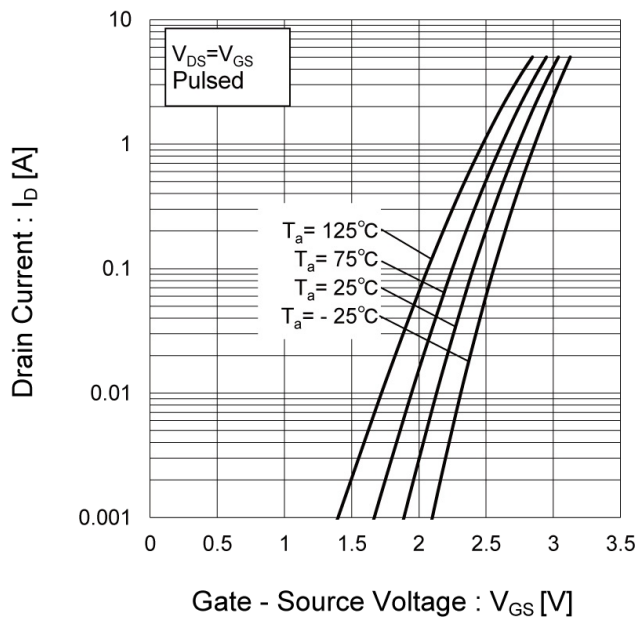


Fig.9 Gate Threshold Voltage vs. Junction Temperature

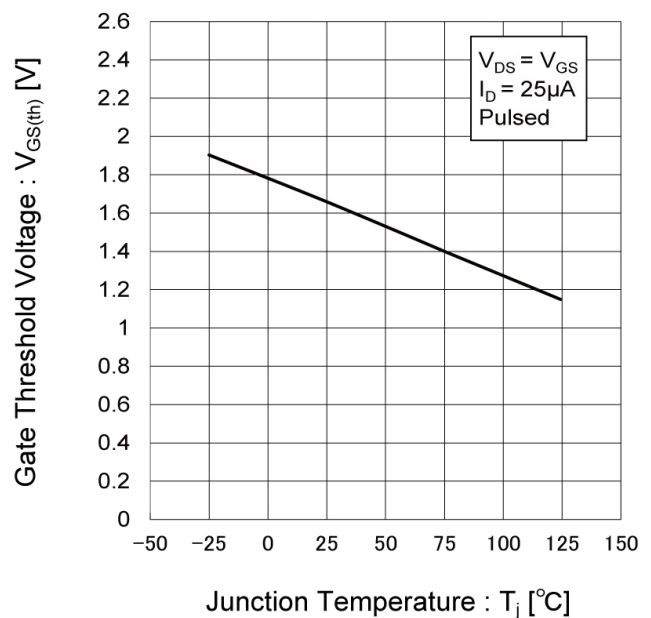
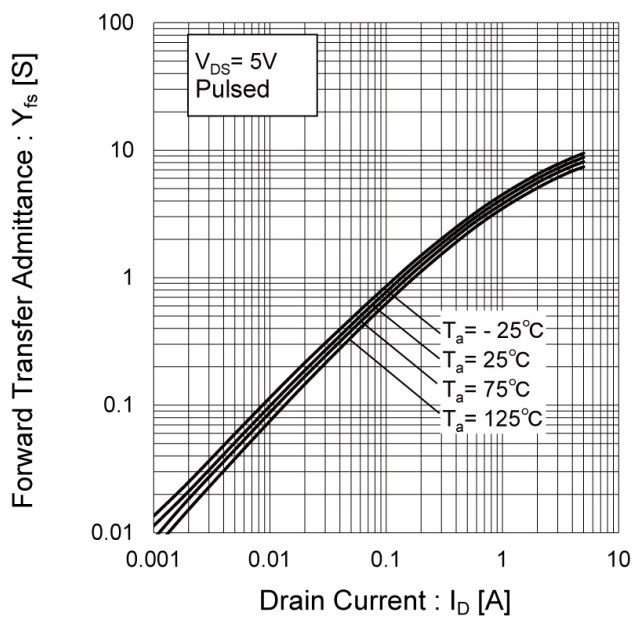


Fig.10 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.11 Drain Current Derating Curve



Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

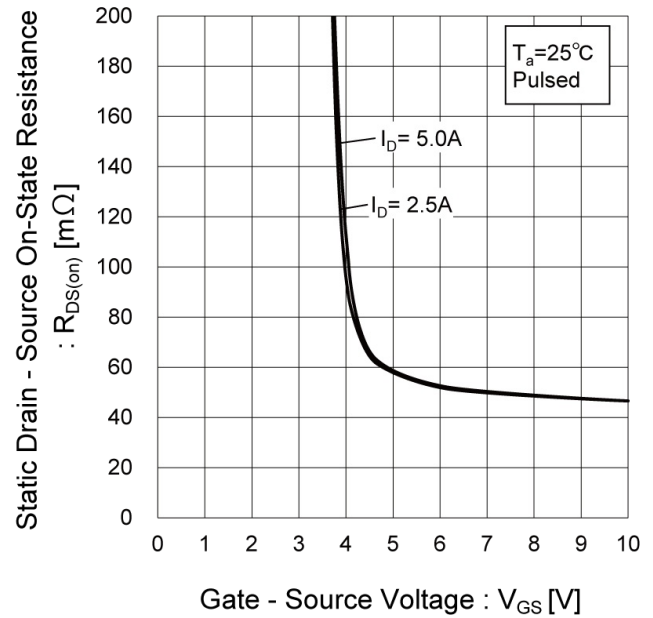
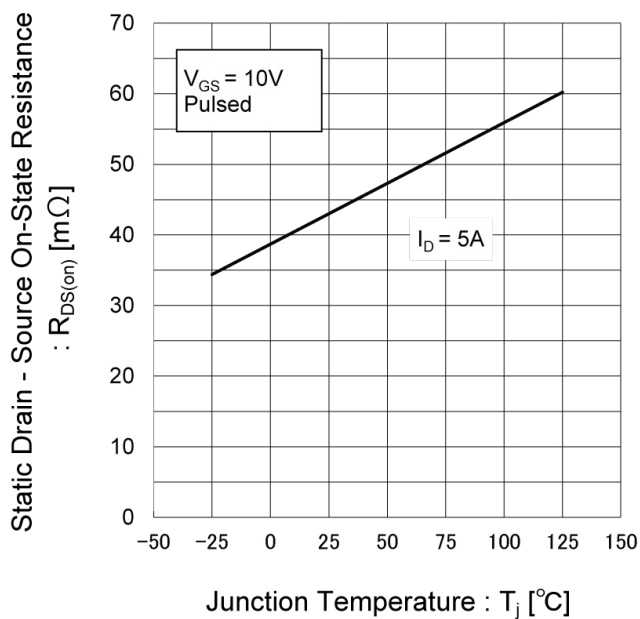


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature



●Electrical characteristic curves

Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

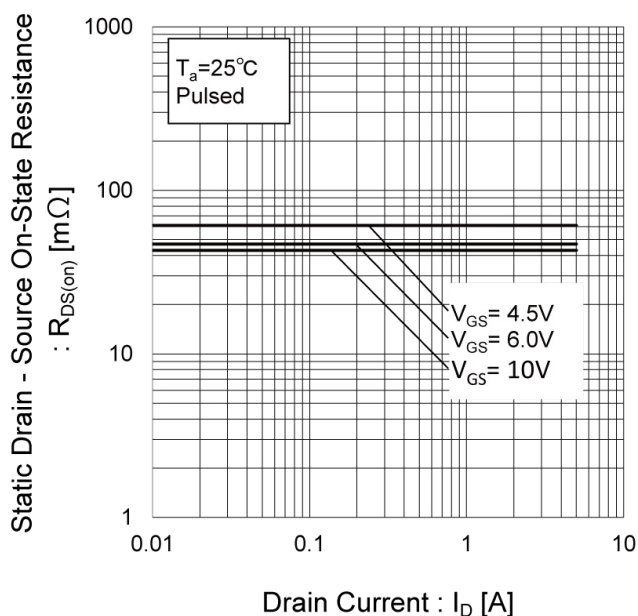


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

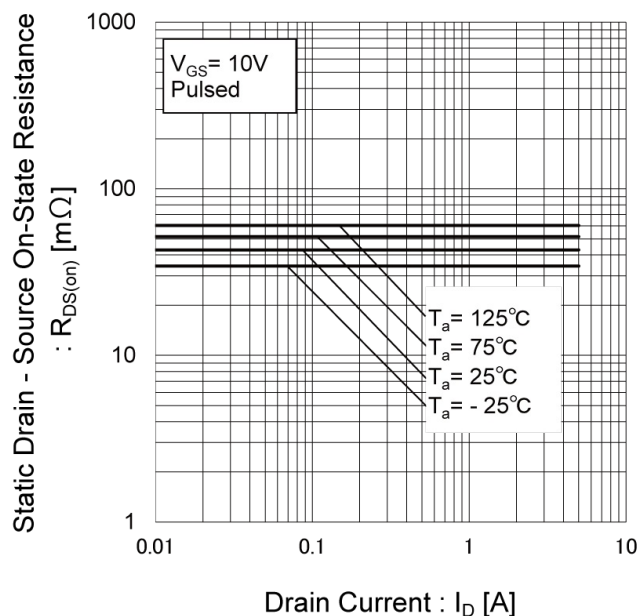


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

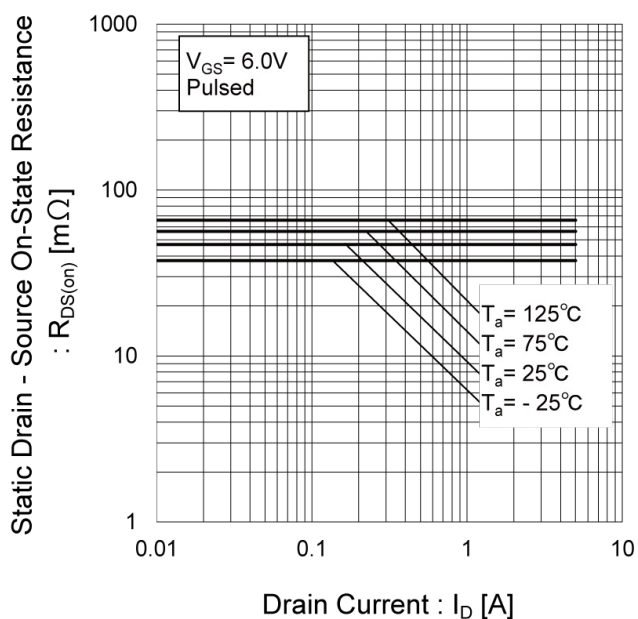
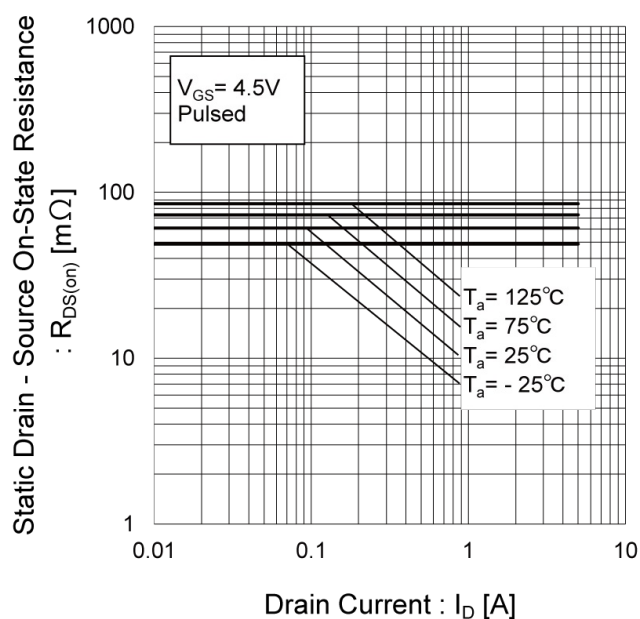


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)



●Electrical characteristic curves

Fig.18 Typical Capacitance vs. Drain - Source Voltage

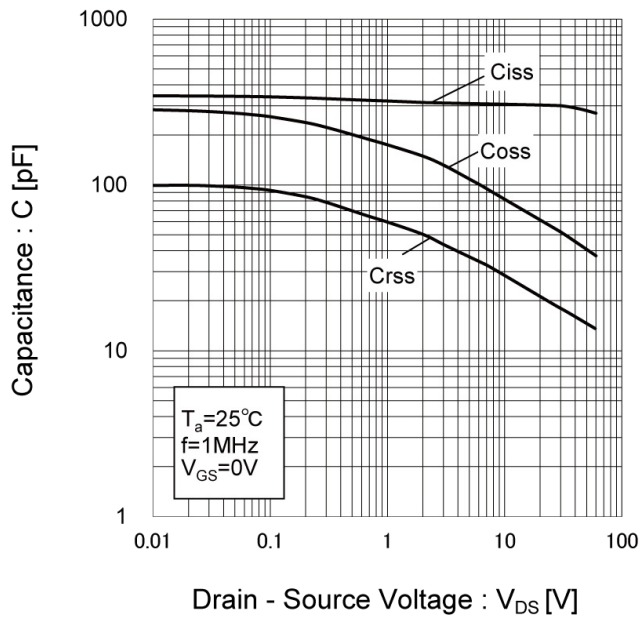


Fig.19 Switching Characteristics

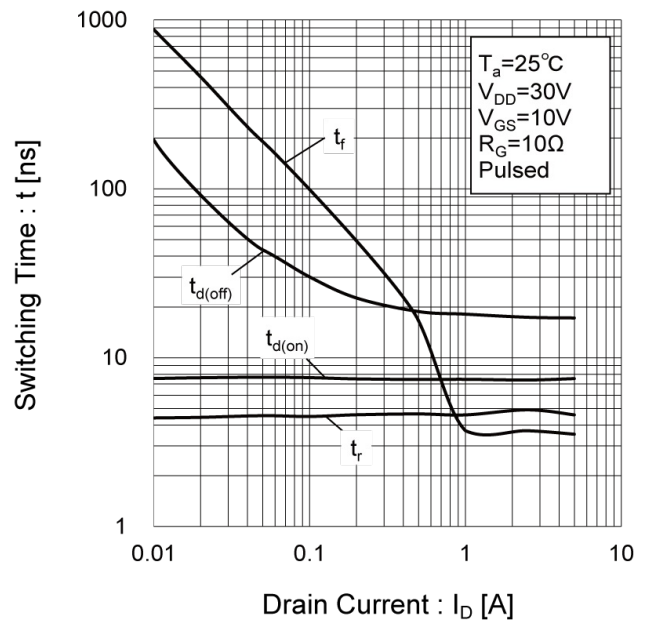


Fig.20 Dynamic Input Characteristics

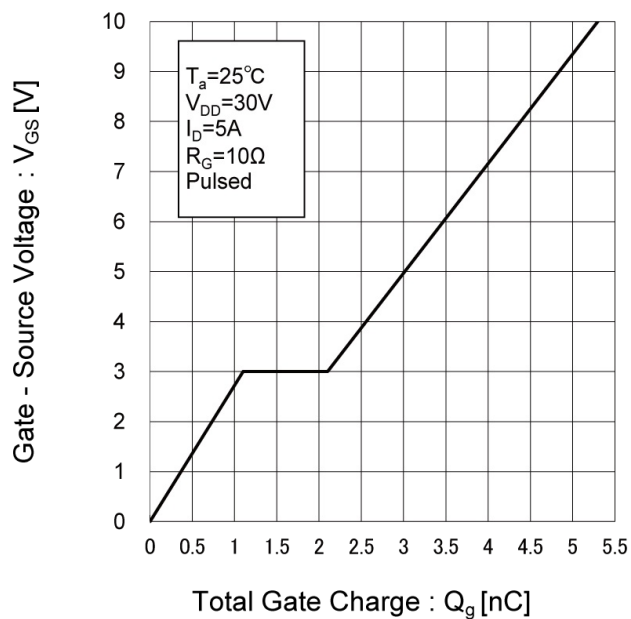
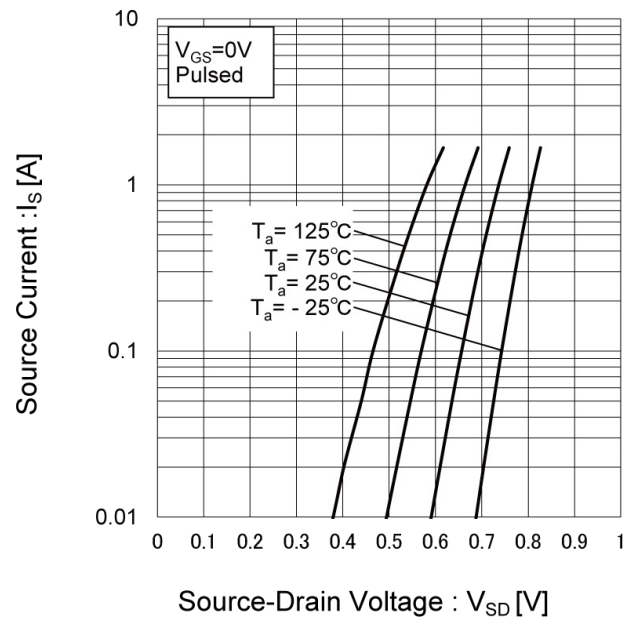


Fig.21 Source Current vs. Source Drain Voltage



● Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

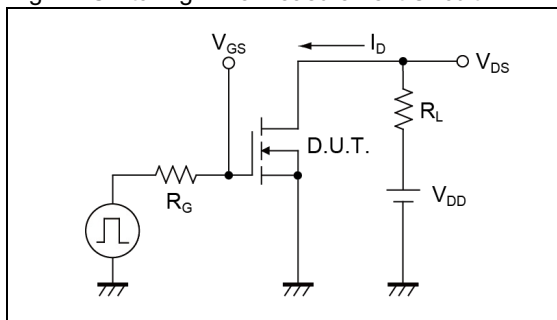


Fig.1-2 Switching Waveforms

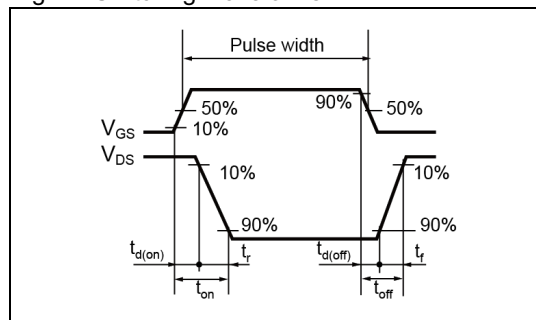


Fig.2-1 Gate Charge Measurement Circuit

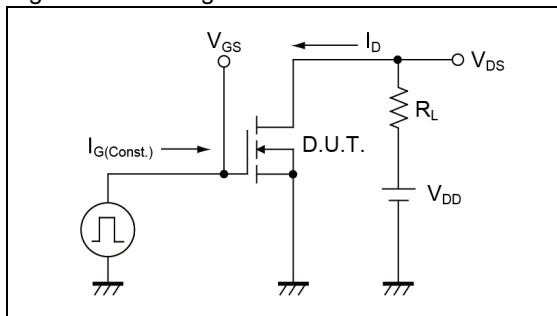


Fig.2-2 Gate Charge Waveform

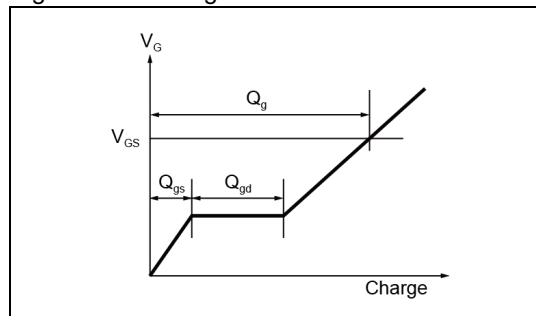


Fig.3-1 AVALANCHE MEASUREMENT CIRCUIT

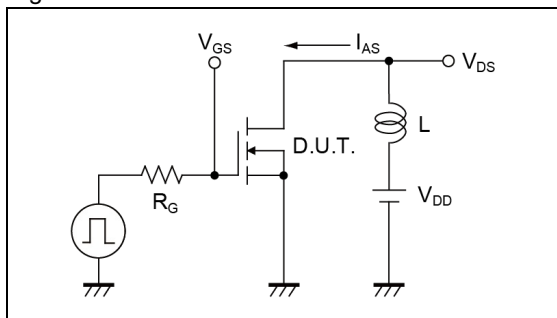
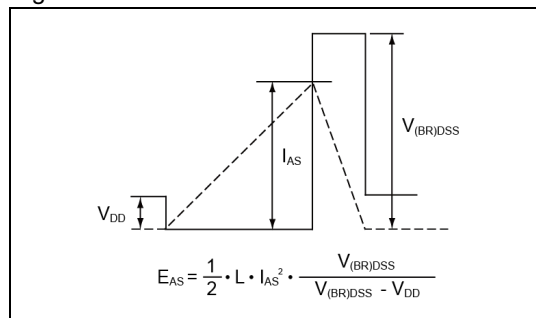


Fig.3-2 AVALANCHE WAVEFORM

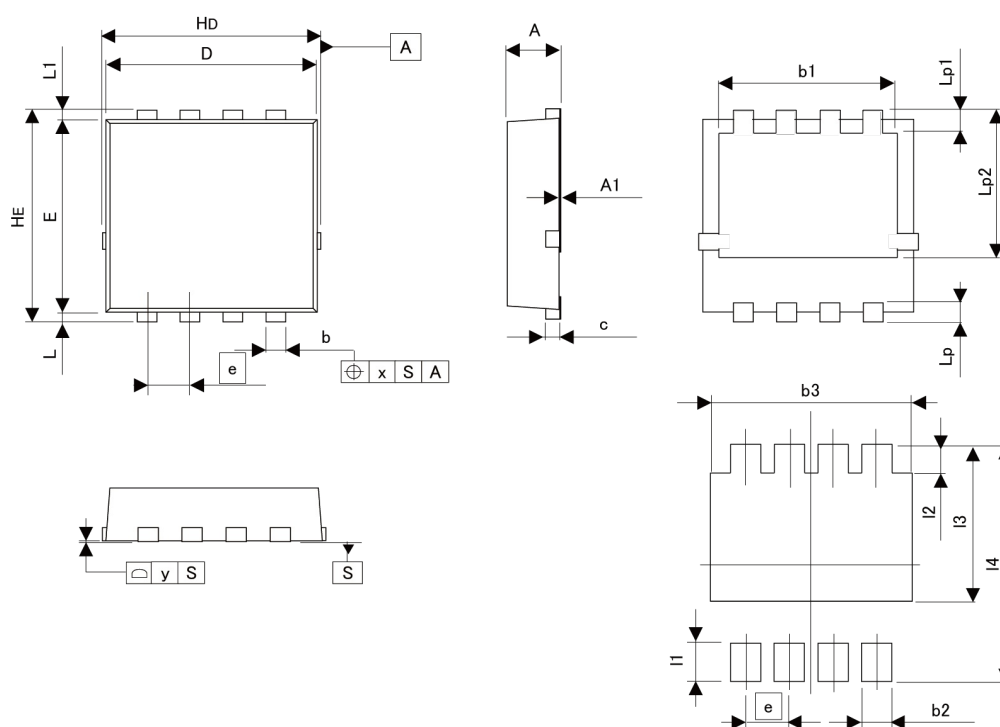


● Notice

This product might cause chip aging and breakdown under the large electrified environment.
Please consider to design ESD protection circuit.

●Dimensions

HSMT8



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.70	0.90	0.028	0.035
A1	0.00	0.05	0.000	0.002
b	0.27	0.37	0.011	0.015
b1	2.50	2.70	0.098	0.106
c	0.10	0.30	0.004	0.012
D	3.10	3.30	0.122	0.130
E	2.90	3.10	0.114	0.122
e	0.65		0.026	
H _D	3.20	3.40	0.126	0.134
H _E	3.20	3.40	0.126	0.134
L	0.07	0.25	0.003	0.010
L ₁	0.07	0.25	0.003	0.010
L _p	0.20	0.40	0.008	0.016
L _{p1}	0.25	0.45	0.010	0.018
L _{p2}	2.20	2.40	0.087	0.094
x	-	0.10	-	0.004
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.47	-	0.019
b3	-	2.70	-	0.106
l1	-	0.50	-	0.020
l2	-	0.55	-	0.022
l3	-	2.40	-	0.094
l4	-	3.40	-	0.134

Dimension in mm/inches

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